NSN 5961-00-432-6574

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-432-6574 **Inclosure Material:** Glass and metal **Overall Length:** 0.312 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 reverse voltage, peak **Current Rating Per Characteristic:** 200.00 amperes zero-gate-voltage source current any acceptable **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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